

# MILITARY HIGH SPEED 16K x 8 CMOS PROM/RPROM

#### **KEY FEATURES**

- Ultra-Fast Access Time
  - 45 ns
- Low Power Consumption
- Fast Programming

- Pin Compatible with Am27S51 and N82HS1281
- Immune to Latch-Up
  Up to 200 mA
- ESD Protection Exceeds 2000 V

#### GENERAL DESCRIPTION

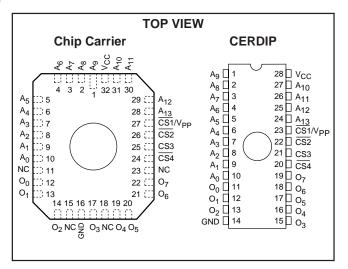
The WS57C51C is a High Performance 128K UV Erasable Electrically Re-Programmable Read Only Memory (RPROM). It is manufactured in an advanced CMOS technology which enables it to operate at Bipolar PROM speeds while consuming only 25% of the power required by its Bipolar counterparts. A further advantage of the WS57C51C over Bipolar PROM devices is the fact that it utilizes a proven EPROM technology. This enables the entire memory array to be tested for switching characteristics and functionality after assembly. Unlike devices which cannot be erased, every WS5751C in a windowed package is 100% tested with worst case test patterns both before and after assembly.

The WS57C51C provides a low power alternative to those design: which are committed to a Bipolar PROM footprint. It is a direct drop-in replacement for a Bipolar PROM of the same architecture (16K x 8). No software, hardware or layout changes need be performed.

### **MODE SELECTION**

PINS MODE	CS1/ V <sub>PP</sub>	CS2	CS3	CS4	v <sub>CC</sub> ,	OUTPUTS
Read	$V_{IL}$	$V_{IL}$	VIH	Vبر	VCC	DOUT
Output Disable	V <sub>IH</sub>	Х		X	Vcc	High Z
Output Disable	Х	V.H	х	Х	VCC	High Z
Output Disable	λ	Х	٧ <sub>IL</sub>	Х	V <sub>CC</sub>	High Z
Output Dicaple	Х	Х	Х	V <sub>IH</sub>	V <sub>CC</sub>	High Z
Program	V <sub>PP</sub>	V <sub>IH</sub>	Х	Х	Vcc	D <sub>IN</sub>
Program Verify	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IL</sub>	Vcc	D <sub>OUT</sub>

### PIN CONFIGURATION



### PRODUCT SELECTION GUIDE

PARAMETER	WS57C51C-45	WS57C51C-55	WS57C51C-70
Address Access Time (Max)	45 ns	55 ns	70 ns
CS to Output Valid Time (Max)	20 ns	25 ns	30 ns

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### ORDERING INFORMATION

PART NUMBER	SPEED	PACKAGE TYPE	PACKAGE DRAWING	OPERATING TEMPERATURE RANGE	WSI MANUFACTURING PROCEDURE
WS57C51C-45CMB	45	32 Pad CLLCC	C2	Military	MIL-STD-883C
WS57C51C-45DMB	45	28 Pin CERDIP, 0.6"	D2	Military	MIL-STD-883C
WS57C51C-45TMB	45	28 Pin CERDIP, 0.3"	T2	Military	MIL-STD-883C
WS57C51C-55CMB	55	32 Pad CLLCC	C2	Military	MIL-STD-883C
WS57C51C-55DMB	55	28 Pin CERDIP, 0.6"	D2	Military	MIL-STD-883C
WS57C51C-55TMB	55	28 Pin CERDIP, 0.3"	T2	Military	MIL-STD-883C

NOTES: 9. The actual part marking will not include the initials "WS."

## PROGRAMMING/ALGORITHMS/ERASURE/PROGRAMMERS

REFER TO PAGE 5-1

The WS57C51C is programmed using Algorithm D shown on page 5-9.

For complete data sheet and electrical specifications see page 2-47.